

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	492	((thin near3 transistor) or TFT) and (substrate with ((Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5))) and (substrate same (crystal\$5 with degree)))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:03
L2	59	L1 and (crystal adj grain adj boundar\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 10:59
L3	2	L2 and (drive\$4 with (normal perpendicular))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 10:59
L4	3	("20030102508" "20030141503" "6177391").PN. OR ("6825494").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/30 11:02
L5	553	((thin near3 transistor) or TFT) and ((Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5)) and (drive\$4 with (normal perpendicular)))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:04
L6	156	5 and (EL)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:04
L7	10	5 and (crystal adj grain adj boundar\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:06
S1	2	((("6177391") or ("6322625"))).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/29 13:54
S4	77424	(thin near3 transistor) or TFT	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 14:05
S16	492	((thin near3 transistor) or TFT) and (substrate with ((Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5))) and (substrate same (crystal\$5 with degree)))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 16:02
S17	76	S16 and (organic and (lumines\$5 luminophor\$3 lumino\$4 EL electroluminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 14:11
S18	23	S17 and (crystal adj grain adj boundar\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/30 11:06

S19	1	("20020043662").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/29 15:38
S20	59	S16 and (crystal adj grain adj boundar\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 15:39
S21	12	S17 and ((crystal adj grain adj boundar\$4) with (degree angle orientation direction))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 15:40
S25	15	((thin near3 transistor) or TFT) and (substrate with ((Polycrystalline adj silicon) polysilicon poly\$Si (silicon with crystal\$5))) and (substrate same (crystal\$5 with degree))) and ((crystal adj grain adj boundar\$5) with (normal perpendicular))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/04/29 16:04
S26	33	("4068020" "4755865" "4868014" "5142344" "5147826" "5242507" "5252507" "5266816" "5275851" "5278093" "5315132" "5318919" "5481121" "5485019" "5491107" "5531182").PN. OR ("5923997").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/29 16:20
S27	1	("20040085268").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/29 16:20
S28	1	("5923997").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/30 10:57